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# Polar2 ${ }^{\text {TM }}$ HiperFET ${ }^{\text {TM }}$ <br> Power MOSFET 

N-Channel Enhancement Mode<br>Avalanche Rated<br>Fast Intrinsic Diode



| Symbol | Test Conditions | Maximum Ratings |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {DSs }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | 500 | V |
| $V_{\text {DGR }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}, \mathrm{R}_{\text {GS }}=1 \mathrm{M} \Omega$ | 500 | V |
| $\mathrm{V}_{\text {GSS }}$ | Continuous | $\pm 30$ | V |
| $\mathbf{V}_{\text {GSM }}$ | Transient | $\pm 40$ | V |
| $\mathrm{I}_{\mathrm{D} 25}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 42 | A |
| $\mathrm{I}_{\mathrm{DM}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$, Pulse Width Limited by $\mathrm{T}_{\mathrm{JM}}$ | 126 | A |
| $\mathrm{I}_{\mathrm{A}}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 42 | A |
| $\mathrm{E}_{\text {As }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 1.4 | J |
| dv/dt | $\mathrm{I}_{S} \leq \mathrm{I}_{\mathrm{DM}}, \mathrm{V}_{\mathrm{DD}} \leq \mathrm{V}_{\mathrm{DSS}}, \mathrm{T}_{\mathrm{J}} \leq 150^{\circ} \mathrm{C}$ | 15 | V/ns |
| $\mathrm{P}_{\mathrm{D}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 830 | W |
| $\mathrm{T}_{\mathrm{J}}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {JM }}$ |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | 1.6 mm (0.062in.) from Case for 10 s | 300 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {sold }}$ | Plastic Body for 10 seconds | 260 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{M}_{\mathrm{d}}$ | Mounting Torque (TO-247) | 1.13 / 10 | Nm/lb.in. |
| Weight | TO-247 | 6 | g |
|  | TO-268 | 4 | g |


| ( $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ Unless Otherwise Specified) |  | Min. | Typ. | Max. |
| :---: | :---: | :---: | :---: | :---: |
| $B V_{\text {DSs }}$ | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=1 \mathrm{~mA}$ | 500 |  | V |
| $\mathrm{V}_{\text {GS(th) }}$ | $\mathrm{V}_{\mathrm{DS}}=\mathrm{V}_{\mathrm{GS}}, \mathrm{I}_{\mathrm{D}}=4 \mathrm{~mA}$ | 2.5 |  | 4.5 V |
| $\mathrm{I}_{\text {Gss }}$ | $\mathrm{V}_{\mathrm{GS}}= \pm 30 \mathrm{~V}, \mathrm{~V}_{\text {DS }}=0 \mathrm{~V}$ |  |  | $\pm 100 \mathrm{nA}$ |
| $\mathrm{I}_{\text {DSS }}$ | $V_{\text {DS }}=V_{\text {DSS }}, V_{G S}=0 \mathrm{~V} \quad \mathrm{~T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  |  | $\begin{array}{rr} 10 & \mu \mathrm{~A} \\ 1 & \mathrm{~mA} \end{array}$ |
| $\underline{\mathrm{R}_{\text {DS(on) }}}$ | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=0.5 \cdot \mathrm{I}_{\mathrm{D} 25}$, Note 1 |  |  | $145 \mathrm{~m} \Omega$ |

## Features

- International Standard Packages
- Fast Intrinsic Diode
- Avalanche Rated
- Low $\mathrm{R}_{\mathrm{DS}(\mathrm{ON})}$ and $\mathrm{Q}_{\mathrm{G}}$
- Low Package Inductance


## Advantages

- High Power Density
- Easy to Mount
- Space Savings

TO-247 (IXFH)

TO-268 (IXFT)


G = Gate $\quad D \quad=$ Drain
$S=$ Source $\quad$ Tab $=$ Drain

## Applications

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- Robotics and Servo Controls



## Source-Drain Diode

Symbol Test Conditions

| ( $\mathrm{J}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ Unless Otherwise Specified) | Min. ${ }^{\text {Typ. }}$ | Max. |
| :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{s}} \quad \mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}$ |  | $42 \quad \mathrm{~A}$ |
| $\mathrm{I}_{\text {SM }} \quad$ Repetitive, Pulse Width Limited by $\mathrm{T}_{\mathrm{JM}}$ |  | 168 A |
| $\mathrm{V}_{\text {SD }} \quad \mathrm{I}_{\mathrm{F}}=\mathrm{I}_{\mathrm{S}}, \mathrm{V}_{\text {GS }}=0 \mathrm{~V}$, Note 1 |  | 1.3 V |
| $\left.\begin{array}{l} \mathbf{t}_{\mathrm{rr}} \\ \mathrm{I}_{\mathrm{RM}} \\ \mathbf{Q}_{\mathrm{RM}} \end{array}\right\} \begin{aligned} & \mathrm{I}_{\mathrm{F}}=21 \mathrm{~A},-\mathrm{di} / \mathrm{dt}=100 \mathrm{~A} / \mu \mathrm{s} \\ & \mathrm{~V}_{\mathrm{R}}=85 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V} \end{aligned}$ | $\begin{array}{r} 12 \\ 1.05 \end{array}$ | $250 \begin{array}{r}\text { ns } \\ \text { A } \\ \\ \mu \mathrm{C}\end{array}$ |

Note 1. Pulse test, $\mathrm{t} \leq 300 \mu \mathrm{~s}$, duty cycle, $\mathrm{d} \leq 2 \%$.

## TO-247 Outline



Terminals: 1 - Gate 2 - Drain
3 - Source

| Dim. | Millimeter |  | Inches |  |
| :--- | ---: | ---: | ---: | ---: |
|  | Min. | Max. | Min. | Max. |
| $\mathrm{A}_{2}$ | 4.7 | 5.3 | .185 | .209 |
| $\mathrm{~A}_{1}$ | 2.2 | 2.54 | .087 | .102 |
| $\mathrm{~A}_{2}$ | 2.2 | 2.6 | .059 | .098 |
| b | 1.0 | 1.4 | .040 | .055 |
| $\mathrm{~b}_{1}$ | 1.65 | 2.13 | .065 | .084 |
| $\mathrm{~b}_{2}$ | 2.87 | 3.12 | .113 | .123 |
| C | .4 | .8 | .016 | .031 |
| D | 20.80 | 21.46 | .819 | .845 |
| E | 15.75 | 16.26 | .610 | .640 |
| e | 5.20 | 5.72 | 0.205 | 0.225 |
| L | 19.81 | 20.32 | .780 | .800 |
| L 1 |  | 4.50 |  | .177 |
| $\varnothing \mathrm{CP}$ | 3.55 | 3.65 | .140 | .144 |
| Q | 5.89 | 6.40 | 0.232 | 0.252 |
| R | 4.32 | 5.49 | .170 | .216 |
| S | 6.15 | BSC | 242 | BSC |

## TO-268 Outline



Fig. 1. Output Characteristics @ $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$


Fig. 3. Output Characteristics $@ \mathrm{~T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$


Fig. 5. $\mathrm{R}_{\mathrm{DS}(o n)}$ Normalized to $\mathrm{I}_{\mathrm{D}}=21 \mathrm{~A}$ Value vs.
Drain Current


Fig. 2. Extended Output Characteristics @ $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$


Fig. 4. $\mathrm{R}_{\mathrm{DS}(\text { on })}$ Normalized to $\mathrm{I}_{\mathrm{D}}=21 \mathrm{~A}$ Value vs. Junction Temperature


Fig. 6. Maximum Drain Current vs.
Case Temperature


Fig. 7. Input Admittance


Fig. 9. Forward Voltage Drop of Intrinsic Diode


Fig. 11. Capacitance


Fig. 8. Transconductance


Fig. 10. Gate Charge


Fig. 12. Maximum Transient Thermal Impedance


IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

